TEXAS INSTRUMENTS
Data sheet acquired from Harris Semiconductor
SCHS026C – Revised September 2003

CD4016B Types

CMOS Quad Bilateral Switch

For Transmission or Multiplexing of Analog or Digital Signals

High-Voltage Types (20-Volt Rating)

■ CD4016B Series types are quad bilateral switches intended for the transmission or multiplexing of analog or digital signals. Each of the four independent bilateral switches has a single control signal input which simultaneously biases both the p and n device in a given switch on or off.

The CD4016 "B" Series types are supplied in 14-lead hermetic dual-in-line ceramic packages (F3A suffix), 14-lead dual-in-line plastic packages (E suffix), 14-lead small-outline packages (M, MT, M96, and NSR suffixes), and 14-lead thin shrink small-outline packages (PW and PWR suffixes).

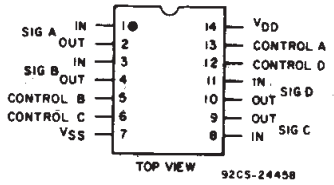
Features:

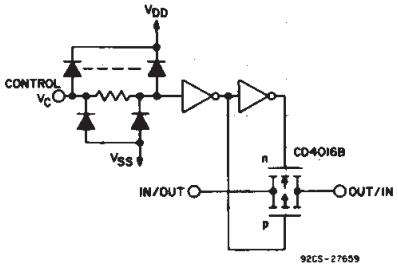
- 20-V digital or ± 10-V peak-to-peak switching
- 280-Ω typical on-state resistance for 15-V operation
- Switch on-state resistance matched to within 10 Ω typ. over 15-V signal-input range
- High on/off output-voltage ratio: 65 dB typ. @ f_{is} = 10 kHz, R_L = 10 kΩ
- High degree of linearity: <0.5% distortion typ. @ f_{is} = 1 kHz, V_{is} = 5 V_{p-p}, $V_{DD}-V_{SS} \geq 10$ V, R_L = 10 kΩ
- Extremely low off-state switch leakage resulting in very low offset current and high effective off-state resistance: 100 pA typ. @ $V_{DD}-V_{SS}$=18 V, T_A=25°C
- Extremely high control input impedance (control circuit isolated from signal circuit: 10^{12} Ω typ.
- Low crosstalk between switches: –50 dB typ. @ f_{is} = 0.9 MHz, R_L = 1 kΩ
- Matched control-input to signal-output capacitance: Reduces output signal transients
- Frequency response, switch on = 40 MHz (typ.)
- 100% tested for quiescent current at 20 V
- Maximum control input current of 1 μA at 18 V over full package temperature range; 100 nA at 18 V at 25°C
- 5-V, 10-V, and 15-V parametric ratings

Applications:

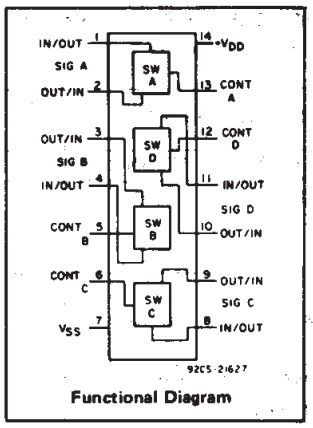
- Analog signal switching/multiplexing
  - Signal gating
  - Squelch control
  - Chopper
  - Modulator
  - Demodulator
  - Commutating switch
- Digital signal switching/multiplexing
- CMOS logic implementation
- Analog-to-digital & digital-to-analog conversion
- Digital control of frequency, impedance, phase, and analog-signal gain

Terminal Assignment





Schematic diagram - 1 of 4 identical sections.



Functional Diagram

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following range:

CHARACTERISTIC	LIMITS		UNITS
	Min.	Max.	
Supply Voltage Range (For T_A = Full Package Temperature Range)	3	18	V

MAXIMUM RATINGS, *Absolute-Maximum Values:*

DC SUPPLY-VOLTAGE RANGE, (V_{DD})
(Voltages referenced to V_{SS} Terminal) ..... -0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS ..... -0.5V to V_{DD} +0.5V
DC INPUT CURRENT, ANY ONE INPUT ..... ±10mA
POWER DISSIPATION PER PACKAGE (P_D):
For T_A = -55°C to +100°C 500mW
For T_A = +100°C to +125°C ..... Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR
FOR T_A = FULL PACKAGE-TEMPERATURE RANGE (All Package Types) 100mW
OPERATING-TEMPERATURE RANGE (T_A) ..... -55°C to +125°C
STORAGE TEMPERATURE RANGE (T_{stg}) ..... -65°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max ..... +265°C

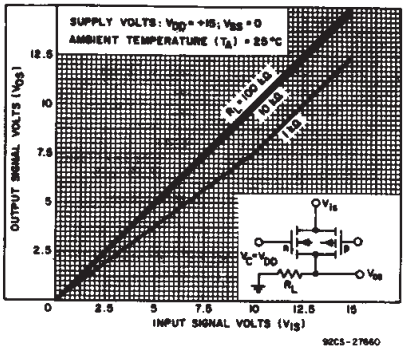


Fig. 1– Typ. on-state characteristics for 1 of 4 switches with V_{DD} = +15 V, V_{SS} = 0 V.

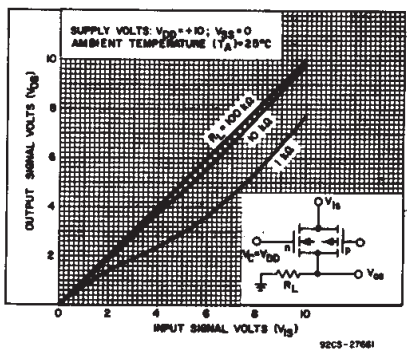


Fig. 2– Typ. on-state characteristics for 1 of 4 switches with V_{DD} = +10 V, V_{SS} = 0 V.

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ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	TEST CONDITIONS		V_{IN} (V)	V_{DD} (V)	LIMITS AT INDICATED TEMPERATURES (°C) −55	−40	+85	+125	+25 Typ.	+25 Max.	UNITS
Quiescent Device Current, I_{DD}			0,5	5	0.25	0.25	7.5	7.5	0.01	0.25	μA
			0,10	10	0.5	0.5	15	15	0.01	0.5	
			0,15	15	1	1	30	30	0.01	1	
			0,20	20	5	5	150	150	0.02	5	
Signal Inputs (V_{is}) and Output (V_{os})											
On-State Resistance, r_{on} Max.	$V_C = V_{DD}$, $R_L = 10k\Omega$ Returned to $\frac{V_{DD}-V_{SS}}{2}$	$V_{is}=V_{DD}$ or V_{SS}		10	600	610	840	960	–	660	Ω
		V_{is}=4.75 to 5.75 V		10	1870	1900	2380	2600	–	2000	
		$V_{is}=V_{DD}$ or V_{SS}		15	360	370	520	600	–	400	
		V_{is}=7.25 to 7.75 V		15	775	790	1080	1230	–	850	
ΔOn-State Resistance Between Any 2 Switches, Δr_{on}	R_L=10 kΩ, $V_C = V_{DD}$			5	–	–	–	–	15	–	Ω
				10	–	–	–	–	10	–	
				15	–	–	–	–	5	–	
Total Harmonic Distortion, THD	$V_C=V_{DD}$ = 5 V, V_{SS} = −5 V, $V_{is(p-p)}$ = 5 V (Sine wave centered on 0 V) R_L=10 kΩ, f_{is}=1 kHz sine wave				–	–	–	–	0.4	–	%
−3dB Cutoff Frequency (Switch on)	$V_C=V_{DD}$=5 V, V_{SS} = −5 V, $V_{is(p-p)}$ =5 V (Sine wave centered on 0 V) R_L = 1 kΩ,				–	–	–	–	40	–	MHz
−50dB Feed-through Frequency (Switch off)	$V_C=V_{SS}$= −5 V, $V_{is(p-p)}$=5 V (Sine wave centered on 0 V) R_L = 1 kΩ				–	–	–	–	1.25	–	MHz
Input/Output Leakage Current (Switch off) I_{is} Max.	V_C = 0 V V_{is} = 18 V, V_{os} = 0 V; V_{is} = 0 V, V_{os} = 18 V			18	±0.1	±0.1	±1	±1	10^{-4}	±0.1	μA
−50 dB Crosstalk Frequency	V_C(A) = V_{DD} = +5 V, V_C(B) = V_{SS} = −5 V, V_{is}(A) = 5 V_{p-p}, 50 Ω source R_L = 1 kΩ				–	–	–	–	0.9	–	MHz
Propagation Delay (Signal Input to Signal Output) t_{pd}	R_L = 200 kΩ $V_C = V_{DD}$, V_{SS} = GND, C_L = 50 pF V_{is} = Square Wave 0 to V_{DD} t_r, t_f = 20 ns			5	–	–	–	–	40	100	ns
				10	–	–	–	–	20	40	
				15	–	–	–	–	15	30	
Capacitance: Input, C_{is}	V_{DD} = +5 V $V_C = V_{SS}$ = −5 V				–	–	–	–	4	–	pF
Output, C_{os}					–	–	–	–	4	–	
Feedthrough, C_{ios}					–	–	–	–	0.2	–	

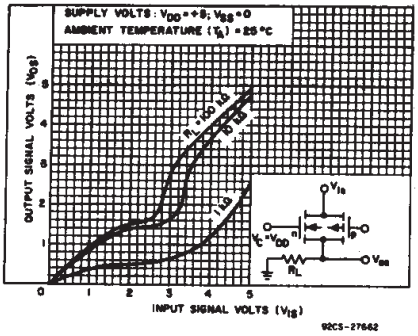


Fig. 3—Typ. on-state characteristics for 1 of 4 switches with V_{DD} = +5 V, V_{SS} = 0 V.

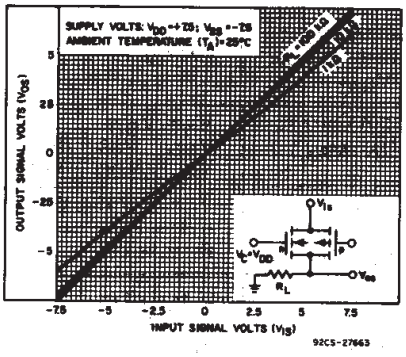


Fig. 4—Typ. on-state characteristics for 1 of 4 switches with V_{DD} = +7.5 V, V_{SS} = −7.5 V.

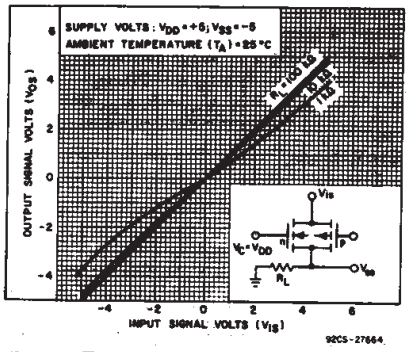


Fig. 5— Typ. on-state characteristics for 1 of 4 switches with V_{DD} = +5 V, V_{SS} = −5 V.

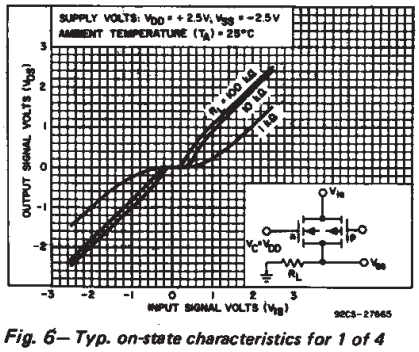


Fig. 6— Typ. on-state characteristics for 1 of 4 switches with V_{DD} = +2.5 V, V_{SS} = −2.5 V.

ELECTRICAL CHARACTERISTICS (cont'd)

CHARACTERISTIC	TEST CONDITIONS	V_{DD} (V)	LIMITS AT INDICATED TEMPERATURES (°C)						UNITS
			−55	−40	+85	+125	+25 Typ.	+25 Max.	
Control (V_C)									
Control Input Low Voltage, V_{ILC} (Max.)	$\|I_{is}\| < 10\,\mu A$ $V_{is} = V_{SS}$, $V_{OS} = V_{DD}$ and $V_{is} = V_{DD}$, $V_{OS} = V_{SS}$	5,10, 15	0.9	0.9	0.4	0.4	–	0.7	V
Control Input High Voltage, V_{IHC}	See Fig. 10	5 10 15	3.5 (Min.) 7 (Min.) 11 (Min.)						V
Input Current, I_{IN} (Max.)	$V_{is} \leq V_{DD}$ $V_{DD} - V_{SS} = 18$ V $V_{CC} \leq V_{DD} - V_{SS}$	18	±0.1	±0.1	±1	±1	$\pm 10^{-5}$	±0.1	μA
Crosstalk (Control Input to Signal Output)	$V_C = 10$ V (Sq. Wave) t_r, $t_f = 20$ ns $R_L = 10$ kΩ	10	–	–	–	–	50	–	mV
Turn-On Propagation Delay	t_r, $t_f = 20$ ns $C_L = 50$ pF $R_L = 1$ kΩ	5 10 15	– – –	– – –	– – –	– – –	35 20 15	70 40 30	ns
Maximum Control Input Repetition Rate	$V_{is} = V_{DD}$, V_{SS} = GND, $R_L = 1$ kΩ to gnd, $C_L = 50$ pF, $V_C = 10$ V (Square wave centered on 5 V) t_r, $t_f = 20$ ns, $V_{os} = ½\ V_{os}$ @ 1 kHz	10	–	–	–	–	10	–	MHz
Input Capacitance, C_{IN}			–	–	–	–	5	7.5	μF

V_{DD} (V)	V_{is} (V)	Switch Input I_{is} (mA) −55°C	−40°C	25°C*	25°C▲	+85°C	+125°C	Switch Output V_{os} (V) Min.	Max.
5	0	0.25	0.2	0.2	0.16	0.12	0.14	–	0.4
5	5	−0.25	−0.2	−0.2	−0.16	−0.12	−0.14	4.6	–
10	0	0.62	0.5	0.5	0.4	0.3	0.35	–	0.5
10	10	−0.62	−0.5	−0.5	−0.4	−0.3	−0.35	9.5	–
15	0	1.8	1.4	1.5	1.2	1	1.1	–	1.5
15	15	−1.8	−1.4	−1.5	−1.2	−1	−1.1	13.5	–

* Plastic package ▲ Ceramic package

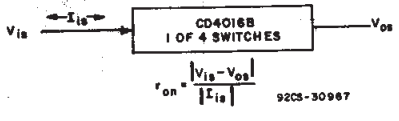


Fig. 10— Determination of r_{on} as a test condition for control input high voltage (V_{IHC}) specification.

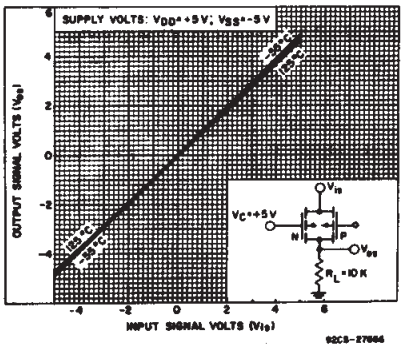


Fig. 7— Typ. on-state characteristics as a function of temp. for 1 of 4 switches with V_{DD} = +5 V, V_{SS} = −5 V.

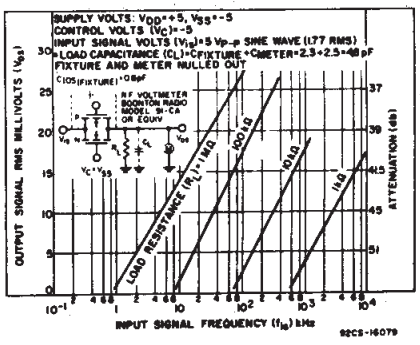


Fig. 8 — Typ. feedthru vs. frequency — switch off.

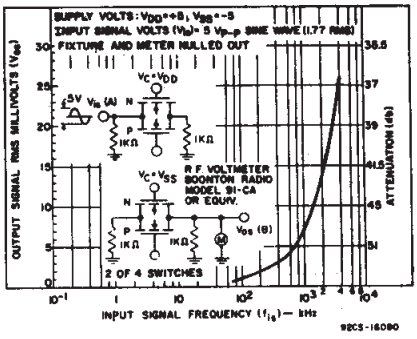


Fig. 9— Typical crosstalk between switch circuits in the same package.

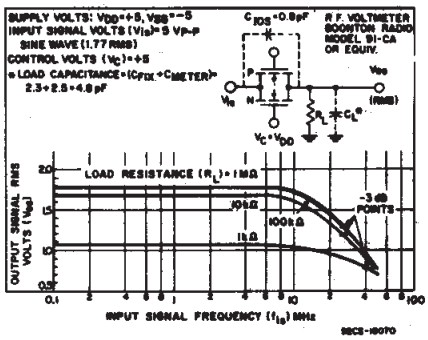


Fig. 11 — Typical frequency response — switch on.

TYPICAL ON-STATE RESISTANCE CHARACTERISTICS, T_A = 25°C

CHARACTERISTIC*	SUPPLY CONDITIONS		LOAD CONDITIONS					
			R_L = 1kΩ		R_L = 10kΩ		R_L = 100kΩ	
	V_{DD} (V)	V_{SS} (V)	VALUE (Ω)	V_{is} (V)	VALUE (Ω)	V_{is} (V)	VALUE (Ω)	V_{is} (V)
r_{on}	+15	0	200	+15	200	+15	180	+15
			200	0	200	0	200	0
r_{on} (max.)	+15	0	300	+11	300	+9.3	320	+9.2
r_{on}	+10	0	290	+10	250	+10	240	+10
			290	0	250	0	300	0
r_{on} (max.)	+10	0	500	+7.4	560	+5.6	610	+5.5
r_{on}	+ 5	0	860	+ 5	470	+ 5	450	+ 5
			600	0	580	0	800	0
r_{on} (max.)	+ 5	0	1.7k	+4.2	7k	+2.9	33k	+2.7
r_{on}	+7.5	−7.5	200	+7.5	200	+7.5	180	+7.5
			200	−7.5	200	−7.5	180	−7.5
r_{on} (max.)	+7.5	−7.5	290	±0.25	280	±25	400	±0.25
r_{on}	+ 5	− 5	260	+ 5	250	+ 5	240	+ 5
			310	− 5	250	− 5	240	− 5
r_{on} (max.)	+ 5	− 5	600	±0.25	580	±0.25	760	±0.25
r_{on}	+2.5	−2.5	590	+2.5	450	+2.5	490	+2.5
			720	-2.5	520	-2.5	520	−2.5
r_{on} (max.)	+2.5	−2.5	232k	±0.25	300k	±0.25	870k	±0.25

* Variation from aperfect switch, r_{on} = 0 Ω.

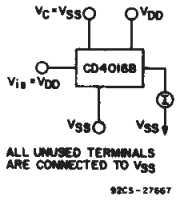


Fig. 12 – Off-state switch input or output leakage current test circuit.

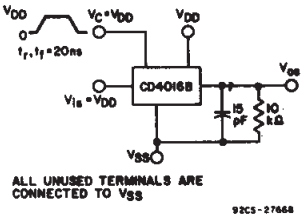
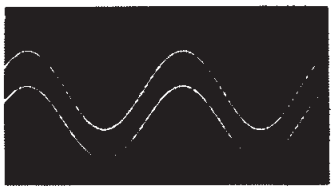


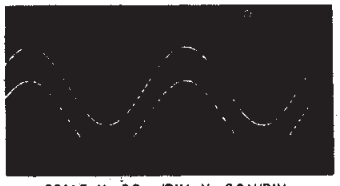
Fig.13 – Test circuit for square-wave response.



SCALE: X = 0.2 ms/DIV Y = 2.0 V/DIV
V_{DD} = V_C = +7.5V, V_{SS} = -7.5V, R_L = 10KΩ
C_L = 15 pF
f_{IS} = 1 KHz V_{IS} = 5V p-p
DISTORTION = 0.2 %

92CS-27612

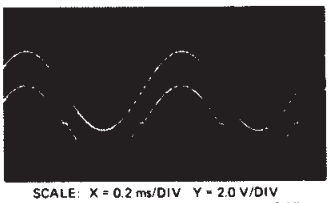
Fig.14 – Typical sine wave response of V_{DD} = +7.5 V, V_{SS} = −7.5 V.



SCALE: X = 0.2 ms/DIV Y = 2.0 V/DIV
V_{DD} = V_C = +5 V, V_{SS} = -5 V, R_L = 10KΩ
C_L = 15 pF
f_{IS} = 1 KHz V_{IS} = 5 V p-p
DISTORTION = 0.4 %

92CS-27613

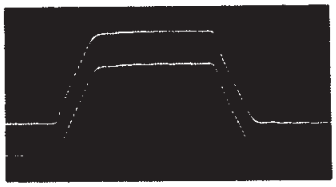
Fig.15 – Typical sine wave response of V_{DD} = +5 V, V_{SS} = −5 V.



SCALE: X = 0.2 ms/DIV Y = 2.0 V/DIV
V_{DD} = V_C = +2.5V, V_{SS} = -2.5V, R_L = 10KΩ
C_L = 15 pF
f_{IS} = 1 KHz V_{IS} = 5V p-p
DISTORTION = 3 %

92CS-27614

Fig.16 – Typical sine wave response of V_{DD} = +2.5 V, V_{SS} = −2.5 V.



SCALE: X = 100 ns/DIV
Y = 5.0 V/DIV

92CS-27615

Fig.17 – Typical square wave response at V_{DD} = V_C = +15 V, V_{SS} = Gnd.

SCALE: X = 100 ns/DIV
Y = 5.0 V/DIV

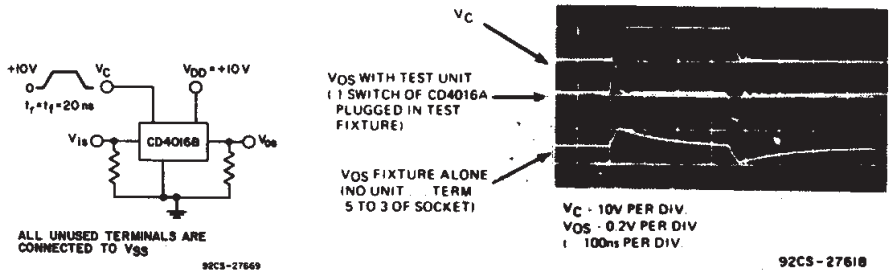
92CS-27616

Fig.18 – Typical square wave response at V_{DD} = V_C = +10 V, V_{SS} = Gnd.

SCALE: X = 100 ns/DIV
Y = 2 V/DIV

92CS-27617

Fig.19 – Typical square wave response at V_{DD} = V_C = +5 V, V_{SS} = Gnd.



(a) (b)

Fig.20 – Crosstalk-control input to signal output.

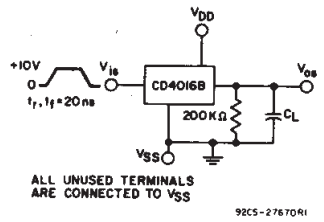


Fig.21 – Propagation delay time signal input (V_{IS}) to signal output (V_{OS}).

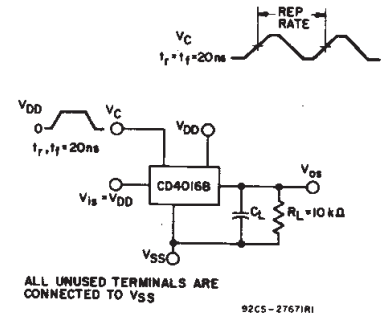


Fig. 22 – Max. control-input repetition rate.

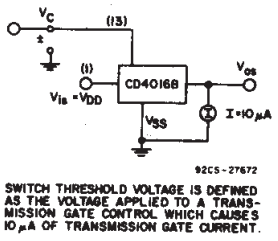


Fig.23 – Switch threshold voltage.

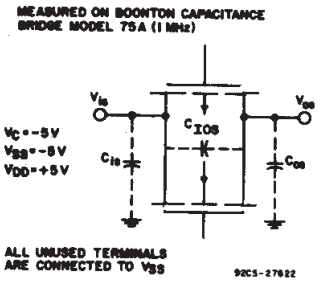


Fig.24 – Capacitance C_{IOS} and C_{OS}.

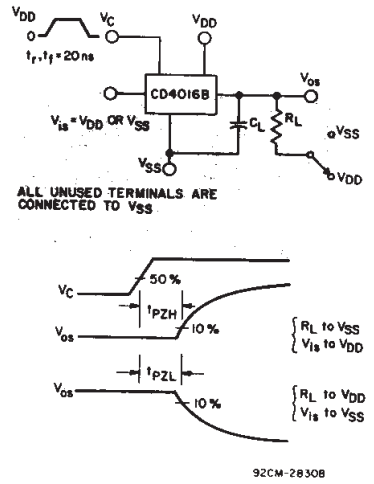
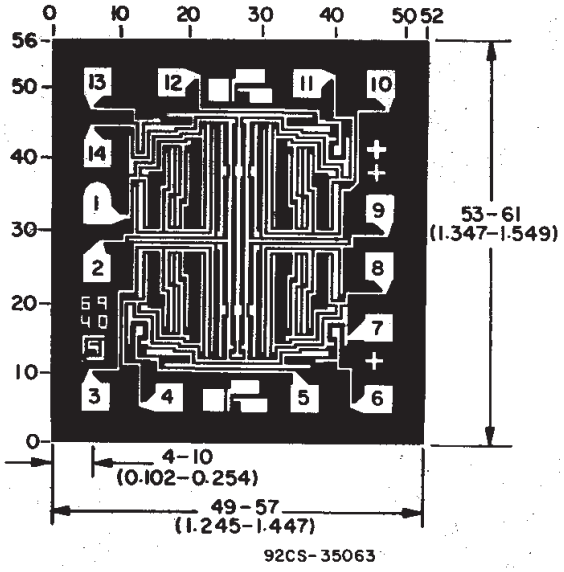


Fig.25 – Turn-On propagation delay-control input.

Dimensions and pad layout for CD4016BH

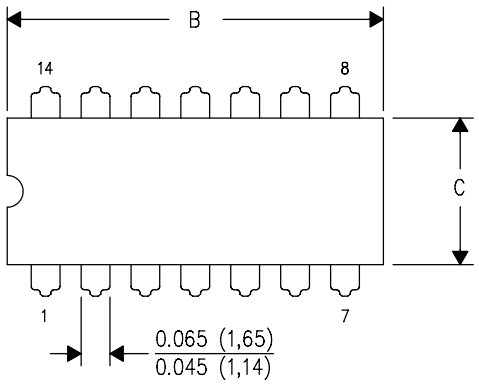


Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

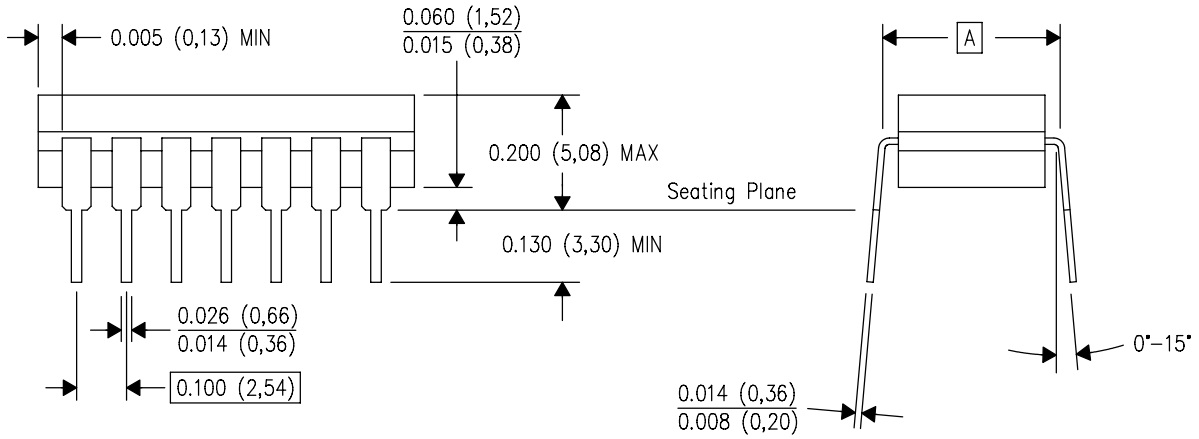
J (R–GDIP–T**)

14 LEADS SHOWN

CERAMIC DUAL IN–LINE PACKAGE



DIM \ PINS **	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



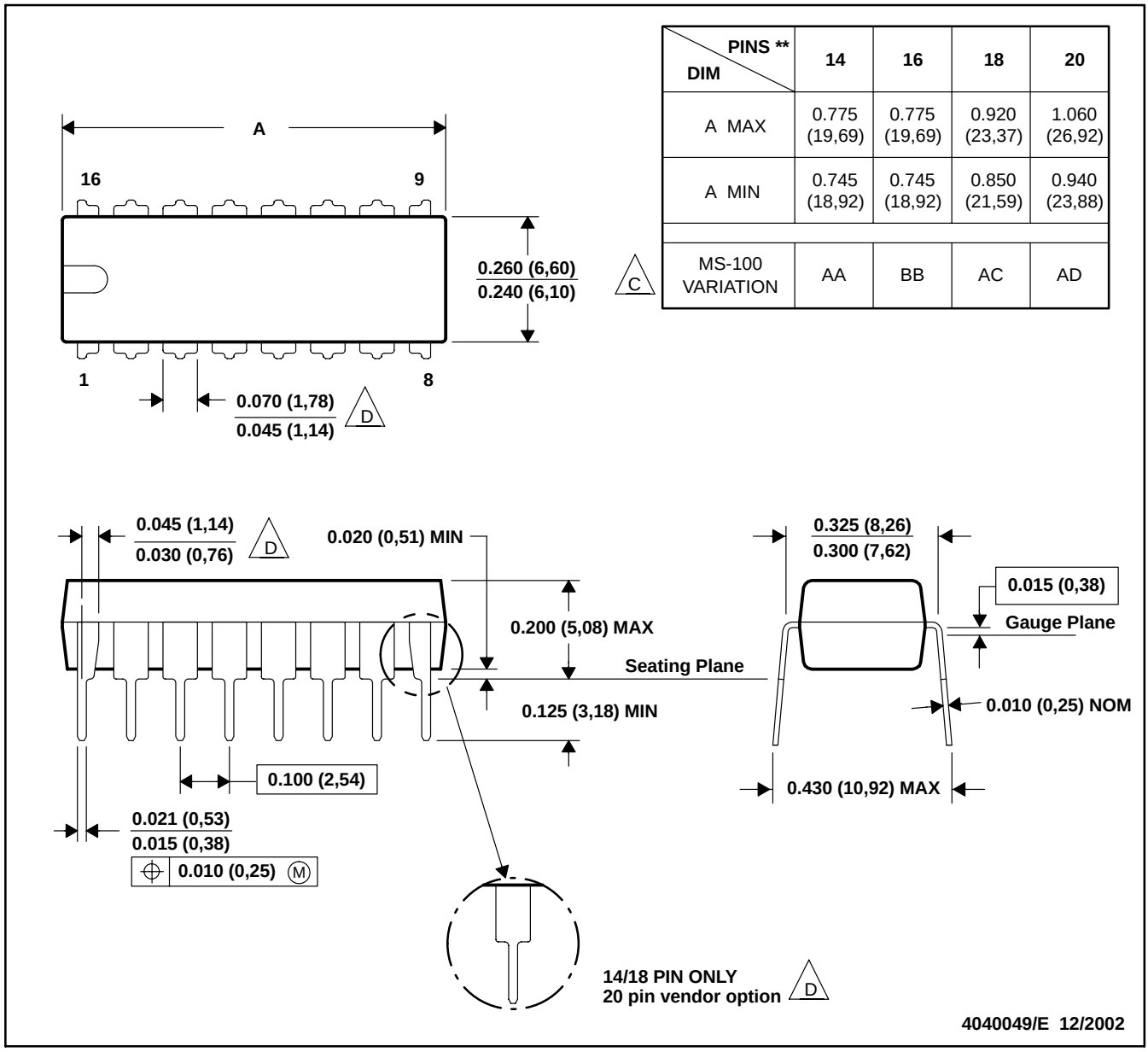
4040083/F 03/03

NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. This package is hermetically sealed with a ceramic lid using glass frit.
D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
E. Falls within MIL STD 1835 GDIP1–T14, GDIP1–T16, GDIP1–T18 and GDIP1–T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



DIM \ PINS **	14	16	18	20
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-100 VARIATION	AA	BB	AC	AD

NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Falls within JEDEC MS-001, except 18 and 20 pin minimum body lrngth (Dim A).

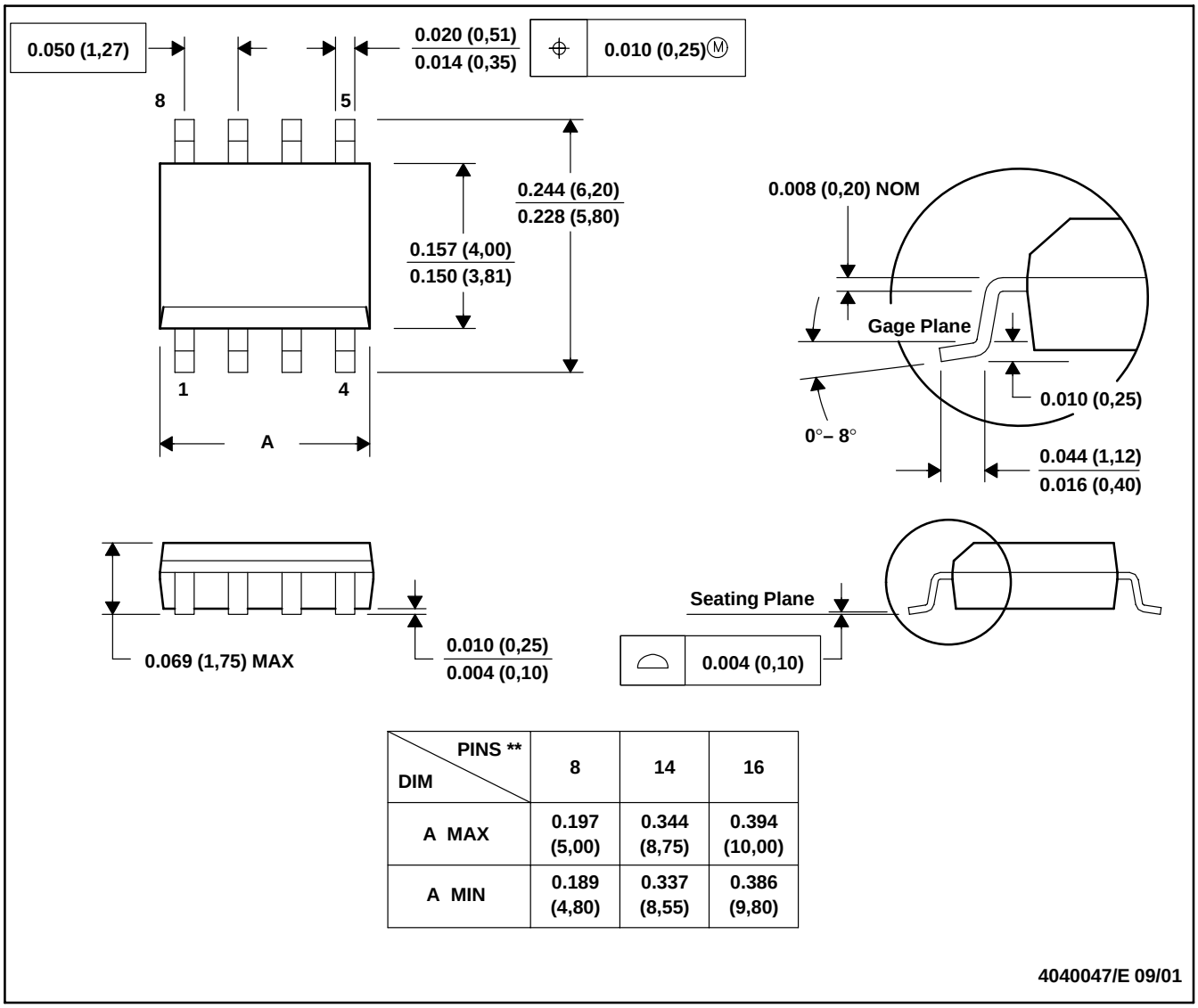
D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

MSOI002B – JANUARY 1995 – REVISED SEPTEMBER 2001

D (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

8 PINS SHOWN



DIM \ PINS **	8	14	16
A MAX	0.197 (5,00)	0.344 (8,75)	0.394 (10,00)
A MIN	0.189 (4,80)	0.337 (8,55)	0.386 (9,80)

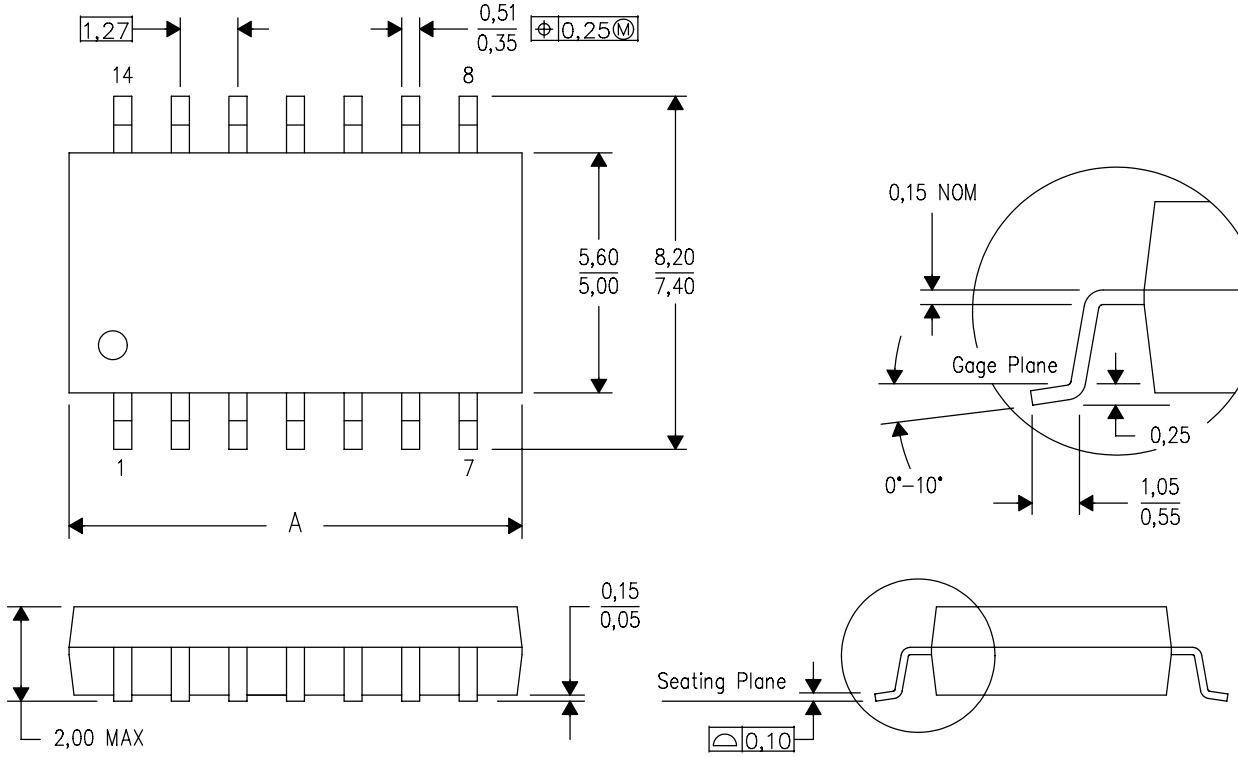
4040047/E 09/01

NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
D. Falls within JEDEC MS-012

MECHANICAL DATA

NS (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14-PINS SHOWN



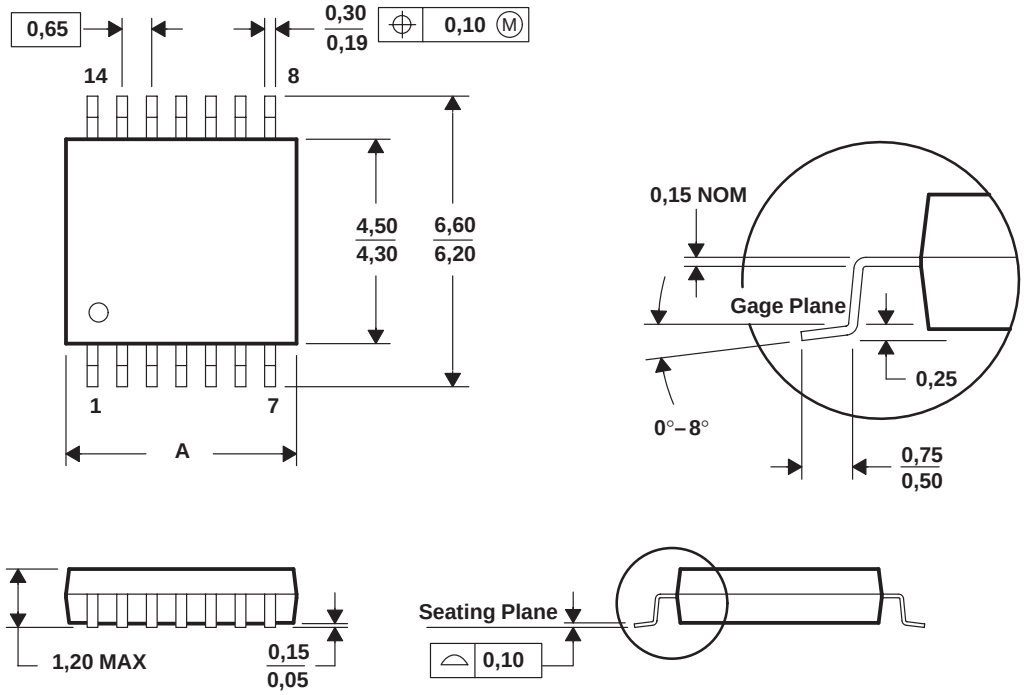
DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

PW (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14 PINS SHOWN



DIM \ PINS **	8	14	16	20	24	28
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

4040064/F 01/97

NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-153

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